Sheet <u>1</u> of <u>2</u>

Form PTO-1449 U.S. Department of (Rev. 8-83) Patent and Trade				Docket No. 0756-2332		Serial No. Not Yet Assigned					
INFORMATION DISCLOSURE STATEMENT					or management						
21.12.02							0490				
	(Use se	veral sheets if necessary)		Applicant: Takeshi FUKADA et al.							
				Applicant: Takeshi FUKADA et al.							
				Filing Date: July 16, 2001		Group: 2825					
U.S. PATENT DOCUMENTS											
Examin er Initial	D	Occument Number	Date	Name	Class	Subclass	Filing Date (if appropriate)				
arom	5,372,860		12/13/1994	Fehlner et al.	427	578	арргорише)				
Am	4,399,015		08/16/1983	Endo et al.	204	192 R.26					
don	4,959,136		09/25/1990	Hatwar	204	192.15					
of on	4,824,712		04/25/1989	Falleroni et al.	428	137					
arom	5,163,220		11/17/1992	Zeto et al.	29	846					
abm	5,094,966		03/10/1992	Yamazaki	43.7438	M 287					
pom	5,296,653		03/22/1994	Kiyota et al.	174	250					
arlon	5,073,451		12/17/1991	Iida et al.	•==========						
SPM	4,985,312		01/15/1991	Furuya et al.	٠						
9m	5,304,518		04/19/1994	Sunahara et al.	- Comments						
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don	5,252,140		10/12/1993	Kobayashi et al.							
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gom	5,165,972		11/24/1992	Porter	65428	6048 1-32					
am	4,116,658		09/26/1978	Sano	65	60-2 42					
Jon	5,480,818		01/02/1996	Matsumoto et al.	487438	<i>4</i> 6. 150					
dom	4,803,183		02/07/1989	Schwetz et al.	501	96. 98.4					
apm	5,475,264		12/12/1995	Sudo et la.	257	723					
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*EXAMIN	NER: Initial	if citation considered	, whether or no	ot citation is in confe	ormance v	vith MPEP 6	09; Draw line				

through citation if not in conformance and not considered. Include copy of this form with next communication to

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	Form PTO-1449 U.S. Department Rev. 8-83) Patent and Tra			Docket No. 0756-2332		Serial No. Not Yet Assigned						
INFOR	MATION DISCLO		TEMENT			;						
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		Ţ	J.S. PATENT	DOCUMENTS		1						
Examin er Initial	Document Number		Date	Name	Class	Subclass	Filing D (if appropris					
arm	5,583,369	5,583,369		Yamazaki et al.			·FFF					
arm	4,435,513			Komeya et al.	—	_						
Som	4,478,785		10/1984	Huseby et al.								
dow	4,963,701		10/1990	Yasumoto et al.								
oron,	5,674,304	,674,304		Fukuda et al.								
Som	5,929,487		07/27/1999	Fukada et al.								
		HOH	PEICN PATE	NT DOCUMENTS	<u> </u>							
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Som	59-121876		07/14/1984	Japan			Abstract	T				
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Som		K. Etemadi, "Thermal Plasma Crystal Growth", 1989 IEEE International Conference on Plasma Science, May 22-24, 1989, pp. 115.										
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Examiner	AMalsan		·	Date Considered	1-12-	2002						
*EXAMINE	R: Initial if citation cons	idered, whether		s in conformance with I	MPEP 609; I		igh citation if	not				
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